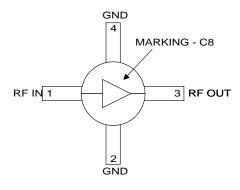
### Typical Applications

- Broadband, Low Noise Gain Blocks
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Final PA for Low Power Applications
- High Reliability Applications
- Broadband Test Equipment

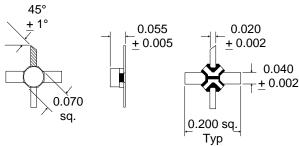
#### **Product Description**

The RF2048 is a general purpose, low cost RF amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as an easily-cascadable  $50\Omega$  gain block. Applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to  $8000 \, \text{MHz}$ . The device is self-contained with  $50\Omega$  input and output impedances and requires only two external DC biasing elements to operate as specified. With a goal of enhanced reliability, the extremely small Micro-X ceramic package offers significantly lower thermal resistance than similar size plastic packages.

Optimum Technology Matching® Applied



Functional Block Diagram



#### NOTES:

- 1. Shaded lead is pin 1.
- 2. Darkened areas are metallization.

Package Style: Micro-X Ceramic

#### **Features**

- DC to 8000MHz Operation
- Internally matched Input and Output
- 12dB Small Signal Gain
- +26dBm Output IP3
- +12dBm Output Power
- Single Positive Power Supply

#### Ordering Information

RF2048 General Purpose Amplifier
RF2048 PCBA Fully Assembled Evaluation Board

 RF Micro Devices, Inc.
 Tel (336) 664 1233

 7625 Thorndike Road
 Fax (336) 664 0454

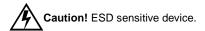
 Greensboro, NC 27409, USA
 http://www.rfmd.com

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GENERAL PURPOSE AMPLIFIERS

#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Current	75	mA
Input RF Power	+15	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-60 to +150	°C



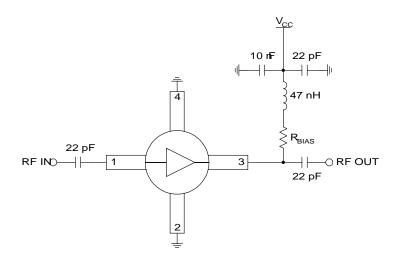
RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

Parameter	Specification		Unit	Condition		
Farameter	Min.	Тур.	Max.	Oilit	Condition	
Overall					T=25 °C, V <sub>D</sub> =3.6V, I <sub>CC</sub> =40 mA	
Frequency Range		DC to 8000		MHz		
Gain		12.2		dB	Freq=100MHz	
		12.1		dB	Freq=1000MHz	
	10	11.8		dB	Freq=2000MHz	
		11.5		dB	Freq=3000MHz	
		11.3			Freq=4000MHz	
		11.0			Freq=6000MHz	
		10.2			Freq=8000MHz	
Gain Flatness		±0.2		dB	100MHz to 2000MHz	
Noise Figure		5.3		dB	Freq=2000MHz	
Input VSWR		1.6:1			In a 50Ω system, DC to 3000MHz	
		1.8:1			In a 50Ω system, 3000MHz to 8000MHz	
Output VSWR		1.5:1			In a 50Ω system, DC to 3000MHz	
		1.9:1			In a 50Ω system, 3000MHz to 8000MHz	
Output IP <sub>3</sub>		+26		dBm	Freq=2000MHz±100kHz, P <sub>TONE</sub> =-5dBm	
Output P <sub>1dB</sub>		+11.7		dBm	Freq=2000MHz	
Reverse Isolation		16.6		dB	Freq=2000MHz	
Thermal					I <sub>CC</sub> =40mA, P <sub>DISS</sub> =137mW	
Theta <sub>JC</sub>		213		°C/W		
Maximum junction temperature		115		°C		
Mean Time Between Failures		1.2x10 <sup>4</sup>		years	T <sub>AMB</sub> =+85°C	
Mean Time Between Failures		6.6x10 <sup>6</sup>		years	T <sub>AMB</sub> =+25°C	
Mean Time Between Failures		1.7x10 <sup>11</sup>		years	T <sub>AMB</sub> =-40°C	
Power Supply					With 22Ω bias resistor	
Operating Device Voltage	3.0	3.6	4.0	V	At pin 3 with I <sub>CC</sub> =40mA	
Operating Current		40		mA		

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Pin	Function	Description	Interface Schematic
1	RF IN	RF input pin. This pin is NOT internally DC blocked. A DC blocking capacitor, suitable for the frequency of operation, should be used in most applications. DC coupling of the input is not allowed, because this will override the internal feedback loop and cause temperature instability.	
2	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
3	RF OUT	RF output and bias pin. Biasing is accomplished with an external series resistor and choke inductor to $V_{CC}$ . The resistor is selected to set the DC current into this pin to a desired level. The resistor value is determined by the following equation: $R = \frac{(V_{SUPPLY} - V_{DEVICE})}{I_{CC}}$ Care should also be taken in the resistor selection to <b>ensure that the current into the part never exceeds 75 mA over the planned operating temperature</b> . This means that a resistor between the supply and this pin is always required, even if a supply near 3.6V is available, to provide DC feedback to prevent thermal runaway. Because DC is present on this pin, a DC blocking capacitor, suitable for the frequency of operation, should be used in most applications. The supply side of the bias network should also be well bypassed.	RF INO
4	GND	Same as pin 2.	

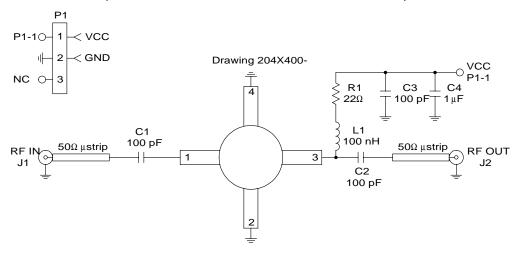
# **Application Schematic**



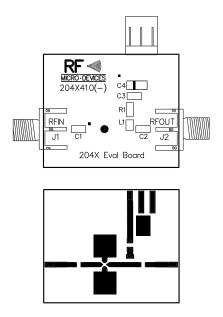
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## **Evaluation Board Schematic**

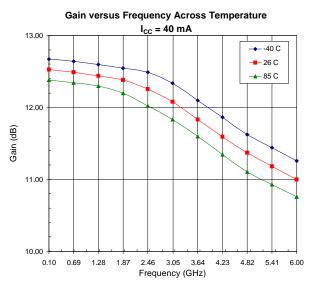
(Download Bill of Materials from www.rfmd.com.)

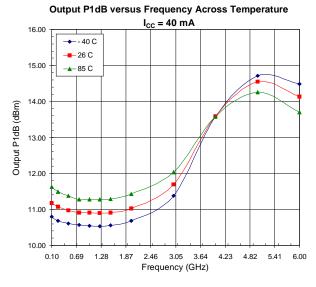


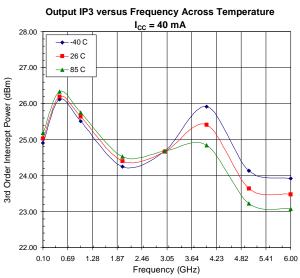
Evaluation Board Layout Board Size 1.195" x 1.000"

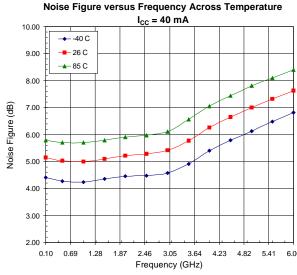


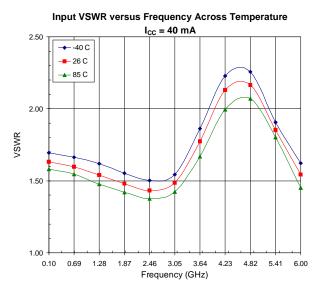
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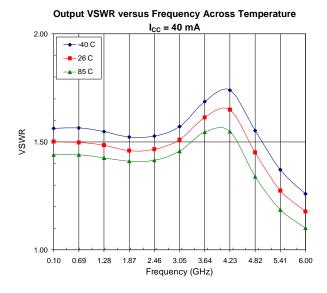




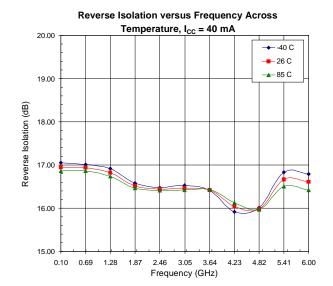








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